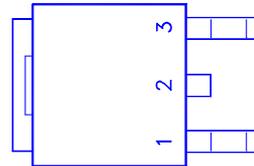
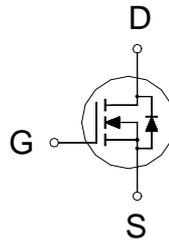


**PRODUCT SUMMARY**

|               |              |       |
|---------------|--------------|-------|
| $V_{(BR)DSS}$ | $R_{DS(ON)}$ | $I_D$ |
| 25            | 12m $\Omega$ | 55A   |



- 1. GATE
- 2. DRAIN
- 3. SOURCE

**ABSOLUTE MAXIMUM RATINGS ( $T_C = 25\text{ }^\circ\text{C}$  Unless Otherwise Noted)**

| PARAMETERS/TEST CONDITIONS   |                                   | SYMBOL         | LIMITS     | UNITS            |
|--|-----------------------------------|----------------|------------|------------------|
| Gate-Source Voltage  |                                   | $V_{GS}$       | $\pm 20$   | V                |
| Continuous Drain Current   | $T_C = 25\text{ }^\circ\text{C}$  | $I_D$          | 55         | A                |
|  | $T_C = 100\text{ }^\circ\text{C}$ |                | 38         |                  |
| Pulsed Drain Current <sup>1</sup>  |                                   | $I_{DM}$       | 150        |                  |
| Avalanche Current  |                                   | $I_{AR}$       | 36         |                  |
| Avalanche Energy   | $L = 0.1\text{mH}$                | $E_{AS}$       | 250        | mJ               |
| Repetitive Avalanche Energy <sup>2</sup>                                 | $L = 0.05\text{mH}$               | $E_{AR}$       | 8.6        |                  |
| Power Dissipation  | $T_C = 25\text{ }^\circ\text{C}$  | $P_D$          | 80         | W                |
|  | $T_C = 100\text{ }^\circ\text{C}$ |                | 41         |                  |
| Operating Junction & Storage Temperature Range                           |                                   | $T_j, T_{stg}$ | -55 to 150 | $^\circ\text{C}$ |
| Lead Temperature ( <sup>1</sup> / <sub>16</sub> " from case for 10 sec.) |                                   | $T_L$          | 275        |                  |

**THERMAL RESISTANCE RATINGS**

| THERMAL RESISTANCE  | SYMBOL          | TYPICAL | MAXIMUM | UNITS                       |
|---------------------|-----------------|---------|---------|-----------------------------|
| Junction-to-Case    | $R_{\theta JC}$ |         | 2.5     | $^\circ\text{C} / \text{W}$ |
| Junction-to-Ambient | $R_{\theta JA}$ |         | 65      |                             |
| Case-to-Heatsink    | $R_{\theta CS}$ | 0.7     |         |                             |

<sup>1</sup>Pulse width limited by maximum junction temperature.

<sup>2</sup>Duty cycle  $\leq 1\%$

**ELECTRICAL CHARACTERISTICS ( $T_C = 25\text{ }^\circ\text{C}$ , Unless Otherwise Noted)**

| PARAMETER                       | SYMBOL        | TEST CONDITIONS  | LIMITS |     |           | UNIT          |
|---------------------------------|---------------|--|--------|-----|-----------|---------------|
|                                 |               |  | MIN    | TYP | MAX       |               |
| <b>STATIC</b>                   |               |  |        |     |           |               |
| Drain-Source Breakdown Voltage  | $V_{(BR)DSS}$ | $V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$                                 | 25     |     |           | V             |
| Gate Threshold Voltage          | $V_{GS(th)}$  | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$                                    | 0.8    | 1.2 | 2.5       |               |
| Gate-Body Leakage               | $I_{GSS}$     | $V_{DS} = 0\text{V}, V_{GS} = \pm 20\text{V}$                              |        |     | $\pm 250$ | nA            |
| Zero Gate Voltage Drain Current | $I_{DSS}$     | $V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$                                  |        |     | 25        | $\mu\text{A}$ |
|                                 |               | $V_{DS} = 20\text{V}, V_{GS} = 0\text{V}, T_C = 125\text{ }^\circ\text{C}$ |        |     | 250       |               |

|   |               |  |    |       |     |    |
|---|---------------|--|----|-------|-----|----|
| On-State Drain Current <sup>1</sup>   | $I_{D(ON)}$   | $V_{DS} = 10V, V_{GS} = 10V$   | 55 |       |     | A  |
| Drain-Source On-State Resistance <sup>1</sup>   | $R_{DS(ON)}$  | $V_{GS} = 7V, I_D = 20A$   |    | 13    | 16  | mΩ |
|   |               | $V_{GS} = 10V, I_D = 30A$  |    | 12    | 15  |    |
| Forward Transconductance <sup>1</sup>   | $g_{fs}$      | $V_{DS} = 15V, I_D = 40A$  |    | 16    |     | S  |
| <b>DYNAMIC</b>  |               |  |    |       |     |    |
| Input Capacitance   | $C_{iss}$     | $V_{GS} = 0V, V_{DS} = 15V, f = 1MHz$  |    | 1400  |     | pF |
| Output Capacitance  | $C_{oss}$     |  |    | 380   |     |    |
| Reverse Transfer Capacitance  | $C_{rss}$     |  |    | 200   |     |    |
| Total Gate Charge <sup>2</sup>  | $Q_g$         | $V_{DS} = 0.5V_{(BR)DSS}, V_{GS} = 10V, I_D = 30A$                             |    | 40    |     | nC |
| Gate-Source Charge <sup>2</sup>   | $Q_{gs}$      |  |    | 12    |     |    |
| Gate-Drain Charge <sup>2</sup>  | $Q_{gd}$      |  |    | 25    |     |    |
| Turn-On Delay Time <sup>2</sup>   | $t_{d(on)}$   | $V_{DS} = 15V, R_L = 1\Omega, I_D \cong 35A, V_{GS} = 10V, R_{GS} = 2.5\Omega$ |    | 9     |     | nS |
| Rise Time <sup>2</sup>  | $t_r$         |  |    | 150   |     |    |
| Turn-Off Delay Time <sup>2</sup>  | $t_{d(off)}$  |  |    | 20    |     |    |
| Fall Time <sup>2</sup>  | $t_f$         |  |    | 30    |     |    |
| <b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (<math>T_C = 25\text{ }^\circ\text{C}</math>)</b> |               |  |    |       |     |    |
| Continuous Current  | $I_S$         |  |    |       | 55  | A  |
| Pulsed Current <sup>3</sup>   | $I_{SM}$      |  |    |       | 170 |    |
| Forward Voltage <sup>1</sup>  | $V_{SD}$      | $I_F = I_S, V_{GS} = 0V$   |    |       | 1.3 | V  |
| Reverse Recovery Time   | $t_{rr}$      | $I_F = I_S, di_F/dt = 100A / \mu S$  |    | 70    |     | nS |
| Peak Reverse Recovery Current   | $I_{RM(REC)}$ |  |    | 200   |     | A  |
| Reverse Recovery Charge   | $Q_{rr}$      |  |    | 0.043 |     | μC |

<sup>1</sup>Pulse test : Pulse Width ≤ 300 μsec, Duty Cycle ≤ 2%.

<sup>2</sup>Independent of operating temperature.

<sup>3</sup>Pulse width limited by maximum junction temperature.

**REMARK: THE PRODUCT MARKED WITH “P50N02LD”, DATE CODE or LOT #**

**TO-252 (DPAK) MECHANICAL DATA**

| Dimension | mm   |      |      | Dimension | mm   |      |      |
|-----------|------|------|------|-----------|------|------|------|
|           | Min. | Typ. | Max. |           | Min. | Typ. | Max. |
| A         | 9.35 |      | 10.1 | H         |      | 0.8  |      |
| B         | 2.2  |      | 2.4  | I         | 6.4  |      | 6.6  |
| C         | 0.48 |      | 0.6  | J         | 5.2  |      | 5.4  |
| D         | 0.89 |      | 1.5  | K         | 0.6  |      | 1    |
| E         | 0.45 |      | 0.6  | L         | 0.64 |      | 0.9  |
| F         | 0.03 |      | 0.23 | M         | 4.4  |      | 4.6  |
| G         | 6    |      | 6.2  | N         |      |      |      |

